

TLV3511-Q1 7ns High-Speed Comparator with Rail-to-Rail Input

1 Features

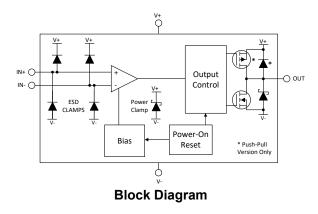
- Qualified for automotive applications
- AEC-Q100 qualified with the following results:
 - Device temperature grade 1: -40°C to 125°C ambient operating temperature range
 - Device HBM ESD classification level H1C _
- Device CDM ESD classification level C6
- Propagation delay: 7ns
- High toggle frequency: 180MHz •
- Wide supply range: 2.7V to 5.5V
- Input offset voltage: +/- 1mV typ. •
- Low supply current: 1.1mA per channel
- Input voltage range extends 300mV beyond either rail
- Internal hysteresis: 2mV
- Power-on-reset provides a known startup condition
- Push-pull output

2 Applications

- **Telematics eCall**
- Automotive head unit
- Instrument Cluster
- On-board (OBC) & wireless chargers

3 Description

The TLV351x-Q1 is a family of 5V single and dual channel comparators with push-pull outputs. The family has an excellent speed-to-power combination with a propagation delay of 7ns and a full supply



voltage range of 2.7V to 5.5V with a quiescent supply current of only 1mA per channel.

All devices include a Power-On Reset (POR) feature. This makes sure the output is in a known state (output LOW) until the minimum supply voltage has been reached before the output responds to the inputs, thus preventing false outputs during system power-up and power down.

Likewise, the TLV351x-Q1 are conveniently available in standard leaded and leadless packages with features such as rail-to-rail inputs, low offset voltage, and large output drive current. These features along with fast response time make the comparators wellsuited for current sensing, zero-cross detection, and a variety of other applications where precision and speed is critical.

All devices are specified for operation across the expanded temperature range of -40°C to 125°C.

Device Information					
PART NUMBER	PACKAGE (1)	BODY SIZE (NOM)			
TLV3511-Q1	SC-70 (5)	1.25mm × 2.00mm			
	SOT-23 (5) (Preview)	1.60mm × 2.90mm			
	SOT (5) (Preview)	1.2mm × 1.5mm			
TLV3512-Q1	VSSOP (8) (Preview)	3.00mm × 3.00mm			
	WSON (8) (Preview)	2.00mm × 2.00mm			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

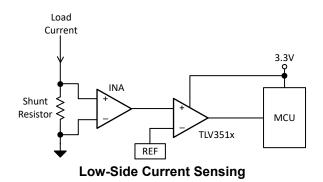




Table of Contents

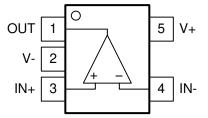
1 Features	1
2 Applications	1
3 Description	
4 Pin Configuration and Functions	3
Pin Configurations: TLV3511 and TLV3512	3
5 Specifications	5
5.1 Absolute Maximum Ratings	5
5.2 ESD Ratings	5
5.3 Recommended Operating Conditions	5
5.4 Thermal Information	
5.5 Electrical Characteristics	6
5.6 Switching Characteristics	6
6 Detailed Description	7
6.1 Overview	7
6.2 Functional Block Diagrams	7
6.3 Feature Description	7
6.4 Device Functional Modes	7

	6.5 Overview	8
7	Application and Implementation	<mark>9</mark>
	7.1 Application Information	
	7.2 Typical Applications	
	7.3 Power Supply Recommendations	
	7.4 Layout	. 13
8	Device and Documentation Support	14
	8.1 Documentation Support	. 14
	8.2 Receiving Notification of Documentation Updates	14
	8.3 Support Resources	. 14
	8.4 Trademarks	
	8.5 Electrostatic Discharge Caution	15
	8.6 Glossary	
9	Revision History	
	0 Mechanical, Packaging, and Orderable	
	Information	. 15



4 Pin Configuration and Functions

Pin Configurations: TLV3511 and TLV3512



DCK, DBV, DRL Packages SC70, SOT-23-5, SOT Top View (Standard "north west" pinout)

Table 4-1. Pin Functions: TLV3511-Q1

P	PIN		DECODIDION		
NAME	NO.	- I/O	DESCRIPTION		
OUT	1	0	Output		
V-	2	-	Negative supply voltage		
IN+	3	I	Non-inverting (+) input		
IN-	4	I	Inverting (-) input		
V+	5	-	Positive supply voltage		



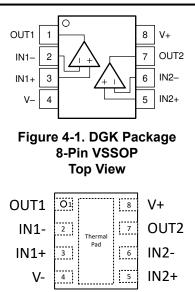


Figure 4-2. DSG Package 8-Pin WSON Top View

Pin Functions: TLV3512-Q1

PIN		I/O	DESCRIPTION	
NAME	NO.		DESCRIPTION	
IN1+	1	I	Noninverting input, channel 1	
IN1–	2	I	Inverting input, channel 1	
IN2-	3	I	Inverting input, channel 2	
IN2+	4	I	Noninverting input, channel 2	
OUT1	7	0	Output, channel 1	
OUT2	6	0	Output, channel 2	
V-	5	-	Negative (lowest) supply or ground	
V+	8	-	Positive (highest) supply	



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Supply voltage V _S = (V+) - (V-)		6	V
Differential input voltage, VID	-6	6	V
Input pins (IN+, IN–) from (V-) (2)	- 0.5	(V+) + 0.5	V
Current into input pins (IN+, IN-)	-10	10	mA
Output (OUT) from (V-)	- 0.5	(V+) + 0.5	V
Output short-circuit current	-100	100	mA
Output short-circuit duration		10	S
Junction temperature, T _J		150	°C
Storage temperature, T _{stg}	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Input terminals are diode-clamped to (V–) and (V+). Input signals that can swing more than 0.5V beyond the supply rails must be current-limited to 10mA or less.

5.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V
V _(ESD)	discharge	Charged-device model (CDM), per AEC Q100-011	±1000	v

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Supply voltage V _S = (V+) - (V-)	2.7	5.5	V
Input voltage range	(V-) - 0.3	(V+) + 0.3	V
Ambient temperature, T _A	-40	125	°C

5.4 Thermal Information

		TLV	TLV3511		
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	DCK (SC70)	UNIT	
		5 PINS	5 PINS		
R _{0JA}	Junction-to-ambient thermal resistance	198.1	220.1	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	95.6	136.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	64.7	65.9	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	32.1	34.5	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	64.3	65.4	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



5.5 Electrical Characteristics

V_{S} = 2.7V to 5V, V_{CM} = V_{S} / 2; at T_{A} = 25°C (unless otherwise noted).	
Typical values are at T₄ = 25°C.	

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC Input Cha	racteristics					
V _{IO}	Input Offset Voltage	V _S = 5V, V _{CM} = V _S / 2		±1	±5	mV
V _{IO}	Input Offset Voltage	$V_{\rm S}$ = 5V, $V_{\rm CM}$ = $V_{\rm S}$ / 2, $T_{\rm A}$ = -40 to 125°C			±6	mV
V _{HYS}	Hysteresis	$V_{\rm S} = 5V, V_{\rm CM} = V_{\rm S} / 2$		2.3		mV
V _{HYS}	Hysteresis	$V_{\rm S}$ = 5V, $V_{\rm CM}$ = $V_{\rm S}$ / 2, $T_{\rm A}$ = -40 to 125°C			3.5	mV
V _{CM}	Common-mode voltage range		(V-) - 0.2		(V+) + 0.2	V
IB	Input bias current	V _S = 5V, V _{CM} = V _S / 2			1	nA
IB	Input bias current	$V_{S} = 5V, V_{CM} = V_{S} / 2, T_{A} = -40$ to 125°C			10	nA
los	Input offset current	V _S = 5V, V _{CM} = V _S / 2			1	nA
C _{IN}	Input capacitance			4		pF
CMRR	Common-mode rejection ratio	$V_{CM} = V_{EE} - 0.2V$ to $V_{CC} + 0.2V$		80		dB
DC Output C	haracteristics					
V _{OH}	Voltage swing from (V+)	V _S = 5V, I _{Source} = 4mA		180	250	mV
V _{OH}	Voltage swing from (V+)	V _S = 5V, I _{Source} = 4mA, -40 to 125C			300	mV
V _{OL}	Voltage swing from (V-)	$V_{S} = 5V, I_{Sink} = 4mA$		180	250	mV
V _{OL}	Voltage swing from (V-)	V _S = 5V, I _{Sink} = 4mA, -40 to 125C			300	mV
		V _S = 5V, sourcing		84		mA
I _{SC}	Short-circuit current	V _S = 5V, sinking		94		ША
Power Suppl	у					
Ι _Q	Supply current / Channel	$V_{\rm S}$ = 2.7V and 5V, no load, $T_{\rm A}$ = -40 to 125°C		1.1	2	mA
V _{POR (postive)}	Power-On Reset Voltage			2.2		V
PSRR	Power Supply Rejection Ratio	$V_{\rm S}$ = 2.7V to 5.5V, $T_{\rm A}$ = -40 to 125°C		93		dB

5.6 Switching Characteristics

For $V_S = 2.7V$ to $V_S = 5V$, $V_{CM} = V_S / 2$; $C_L = 15pF$ at $T_A = 25^{\circ}C$ (Unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PHL}	Propagation delay time, high to- low	Midpoint of input to midpoint of output, V_{OD} = 10mV		12		ns
t _{PHL}	Propagation delay time, high to- low	Midpoint of input to midpoint of output, V_{OD} = 50mV		7	9	ns
t _{PLH}	Propagation delay time, low-to high	Midpoint of input to midpoint of output, V_{OD} = 10mV		12		ns
t _{PLH}	Propagation delay time, low-to high	Midpoint of input to midpoint of output, V_{OD} = 50mV		7	9	ns
PWin	Minimum input pulse width	Voverdrive = Vunderdrive = 50mV PWout = 90% of PWin		5		ns
f _{TOGGLE}	Input toggle frequency	$\label{eq:VIN} \begin{array}{l} V_{IN} = 200 m V_{PP} \mbox{ Sine Wave,} \\ When output high reaches 90\% \mbox{ of } V_{CC} \mbox{ - } V_{EE} \\ \mbox{ or output low reaches 10\% of } V_{CC} \mbox{ - } V_{EE} \end{array}$		180		MHz
t _R	Rise time	Measured from 20% to 80%		1.5		ns
t _F	Fall time	Measured from 20% to 80%		1.5		ns
t _{ON}	Power-up time	During power on, (V+) must exceed 2.2V for 4μ s before the output will reflect the input.		2.5		μs



6 Detailed Description

6.1 Overview

The TLV351x-Q1 devices are high-speed comparators with push-pull outputs.

6.2 Functional Block Diagrams

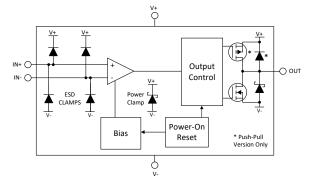


Figure 6-1. Block Diagram

6.3 Feature Description

The TLV351x-Q1 consumes 1mA per channel with 7ns of propagation delay. The TLV351x-Q1 detects fast voltage and current transients while maintaining low power consumption with single-ended, push-pull outputs.

6.4 Device Functional Modes

6.4.1 Inputs

The inputs incorporate internal ESD protection circuits to (V+) and (V-). Voltages on the inputs are limited to 0.3V beyond the rails.

When connecting to a low impedance source such as a power supply or buffered reference line, TI recommends adding a current-limiting resistor in series with the input to limit any transient currents if the clamps conduct. Limit the current to 10mA or less. One form of series resistance is any resistive input dividers or networks.

6.4.1.1 Unused Inputs

If a channel is not to be used, DO NOT tie the inputs together. Due to the high equivalent bandwidth and low offset voltage, tying the inputs directly together can cause high frequency oscillations as the device triggers on it's own internal wideband noise. Instead, the inputs can be tied to any available voltage that resides within the specified input voltage range and provides a minimum of 50mV differential voltage. For example, one input can be grounded and the other input connected to a reference voltage, or even (V+).

6.4.2 Internal Hysteresis

The device hysteresis transfer curve is shown below. This curve is a function of three components: V_{TH} , V_{OS} , and V_{HYST} :

- V_{TH} is the actual set voltage or threshold trip voltage.
- V_{OS} is the internal offset voltage between V_{IN+} and V_{IN-}. This voltage is added to V_{TH} to form the actual trip
 point at which the comparator must respond to change output states.
- V_{HYST} is the internal hysteresis (or trip window) that is designed to reduce comparator sensitivity to noise.

(typically 2mV for the TLV351x-Q1 family)



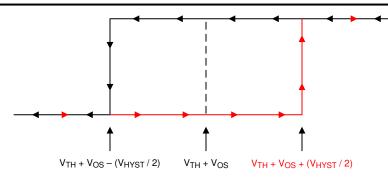


Figure 6-2. Hysteresis Transfer Curve

6.4.3 Outputs

The TLV351x-Q1 features a push-pull output stage capable of both sinking and sourcing current. This allows driving loads such as LED's and MOSFET gates, as well as eliminating the need for a power-wasting external pull-up resistor. The push-pull output must never be connected to another output.

Directly shorting the output to the supply rails ((V+) when output "low" or (V-) when output "High") can result in thermal runaway and eventual device destruction. If output shorts are possible, a series current limiting resistor is recommended to limit the power dissipation.

Unused push-pull outputs must be left floating, and never tied to a supply, ground, or another output.

6.4.4 ESD Protection

The inputs and outputs incorporate internal ESD protection circuits to (V+) and (V-).

Voltages on the inputs are limited to 0.3V beyond the rails. If the inputs are to be connected to a low impedance source, such as a power supply or buffered reference line, TI recommends adding a current-limiting resistor in series with the input to limit any transient currents in case the clamps conduct. Limit the current to 10mA or less.

6.4.5 Power-On Reset (POR)

The TLV351x-Q1 devices have an internal Power-on-Reset (POR) circuit for known start-up or power-down conditions. While the power supply (V+) is ramping up or ramping down, the POR circuitry is activated for up to 2.5us after the V_{POR} of 2.2V is crossed. When the supply voltage is equal to or greater than the minimum supply voltage, and after the delay period, the comparator output reflects the state of the differential input (V_{ID}).

For the TLV351x-Q1 devices, the output is held low during the POR period (t_{on}) as shown below.

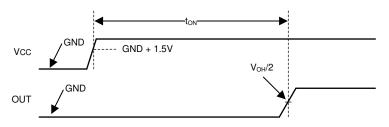


Figure 6-3. Power-On Reset Timing Diagram

6.5 Overview

The TLV351x-Q1 devices are high-speed comparators with push-pull outputs.



7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Basic Comparator Definitions

7.1.1.1 Operation

The basic comparator compares the input voltage (V_{IN}) on one input to a reference voltage (V_{REF}) on the other input. In the example below, if V_{IN} is less than V_{REF} , the output voltage (V_O) is logic low (V_{OL}). If V_{IN} is greater than V_{REF} , the output voltage (V_O) is at logic high (V_{OH}). Likewise, the table below summarizes the output conditions. The output logic can be inverted by simply swapping the input pins.

Table 7-1. Output Conditions			
Inputs Condition	Output		
IN+ > IN-	HIGH (V _{OH})		
IN+ = IN-	Indeterminate (chatters - see Hysteresis)		
IN+ < IN-	LOW (V _{OL})		

7.1.1.2 Propagation Delay

There is a delay between from when the input crosses the reference voltage and the output responds. This is called the Propagation Delay. Propagation delay can be different between high-to low and low-to-high input transitions. This is shown as t_{pLH} and t_{pHL} in the figure below and is measured from the mid-point of the input to the midpoint of the output.

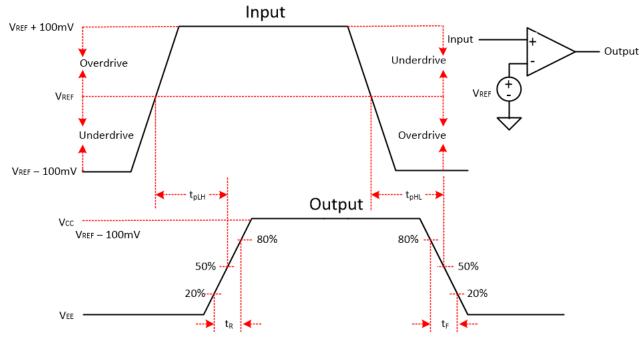


Figure 7-1. Comparator Timing Diagram



7.1.1.3 Overdrive Voltage

The overdrive voltage, V_{OD} , is the amount of input voltage beyond the reference voltage (and not the total input peak-to-peak voltage). The overdrive voltage is 100mV as shown in the above example. The overdrive voltage can influence the propagation delay (t_p). The smaller the overdrive voltage, the longer the propagation delay, particularly when <100mV. If the fastest speeds are desired, it is recommended to apply the highest amount of overdrive possible.

The risetime (t_r) and falltime (t_f) is the time from the 20% and 80% points of the output waveform.

7.1.2 Hysteresis

The basic comparator configuration may produce a noisy "chatter" output if the applied differential input voltage is near the comparator's offset voltage. This usually occurs when the input signal is moving very slowly across the switching threshold of the comparator. This problem can be prevented by adding external hysteresis to the comparator.

Since the TLV351x-Q1 only have a minimal amount of internal hysteresis of 2mV, external hysteresis can be applied in the form of a positive feedback loop that adjusts the trip point of the comparator depending on its current output state.

The hysteresis transfer curve is shown below. This curve is a function of three components: V_{TH} , V_{OS} , and V_{HYST} :

- V_{TH} is the actual set voltage or threshold trip voltage.
- V_{OS} is the internal offset voltage between V_{IN+} and V_{IN-}. This voltage is added to V_{TH} to form the actual trip point at which the comparator must respond to change output states.
- V_{HYST} is the hysteresis (or trip window) that is designed to reduce comparator sensitivity to noise.

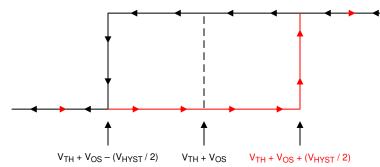


Figure 7-2. Hysteresis Transfer Curve

For more information, please see Application Note SBOA219 "Comparator with and without hysteresis circuit".

7.1.2.1 Inverting Comparator With Hysteresis

The inverting comparator with hysteresis requires a three-resistor network that is referenced to the comparator supply voltage (V_{CC}), as shown below.

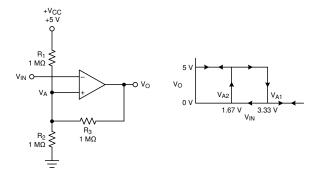


Figure 7-3. TLV351x-Q1 in an Inverting Configuration With Hysteresis

The equivalent resistor networks when the output is high and low are shown below.

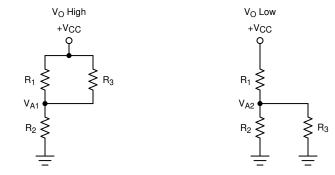


Figure 7-4. Inverting Configuration Resistor Equivalent Networks

When V_{IN} is less than V_A , the output voltage is high (for simplicity, assume V_O switches as high as V_{CC}). The three network resistors can be represented as R1 || R3 in series with R2, as shown above on the left.

The equation below defines the high-to-low trip voltage (V_{A1}).

$$V_{A1} = V_{CC} \times \frac{R2}{(R1 \parallel R3) + R2}$$
(1)

When V_{IN} is greater than V_A , the output voltage is low. In this case, the three network resistors can be presented as R2 || R3 in series with R1, as shown above on the right.

Use equation below to define the low to high trip voltage (V_{A2}).

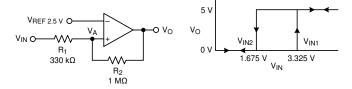
$$V_{A2} = V_{CC} \times \frac{R2 || R3}{R1 + (R2 || R3)}$$
(2)

The equation below defines the total hysteresis provided by the network.

$$\Delta V_{A} = V_{A1} - V_{A2} \tag{3}$$

7.1.2.2 Non-Inverting Comparator With Hysteresis

A non-inverting comparator with hysteresis requires a two-resistor network and a voltage reference (V_{REF}) at the inverting input, as shown below.





The equivalent resistor networks when the output is high and low are shown below.



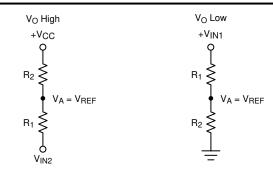


Figure 7-6. Non-Inverting Configuration Resistor Networks

When V_{IN} is less than $V_{REF,}$, the output is low. For the output to switch from low to high, V_{IN} must rise above the V_{IN1} threshold. Use the equation below to calculate V_{IN1} .

$$V_{IN1} = R1 \times \frac{V_{REF}}{R2} + V_{REF}$$
(4)

When V_{IN} is greater than V_{REF} , the output is high. For the comparator to switch back to a low state, V_{IN} must drop below V_{IN2} . Use equation below to calculate V_{IN2} .

$$V_{\rm IN2} = \frac{V_{\rm REF} \left({\rm R1 + R2} \right) - V_{\rm CC} \times {\rm R1}}{{\rm R2}}$$
(5)

The hysteresis of this circuit is the difference between V_{IN1} and V_{IN2} , as shown below.

$$\Delta V_{\rm IN} = V_{\rm CC} \times \frac{\rm R1}{\rm R2}$$
(6)

For more information, please see Application Notes SNOA997 "Inverting comparator with hysteresis circuit" and SBOA313 "Non-Inverting Comparator With Hysteresis Circuit".

7.2 Typical Applications

7.2.1 Low-Side Current Sensing

The figure below shows a simple low-side current sensing circuit using a high-speed comparator. Since this design does not utilze an amplifier, the response time is only limited by the propagation delay of the comparator. With faster response time, the design is well-suited for short-circuit detection when speed is more important than accuracy. When the voltage across the shunt resistor reaches the critical over-current threshold created by R1 and R2, the comparator output changes state.

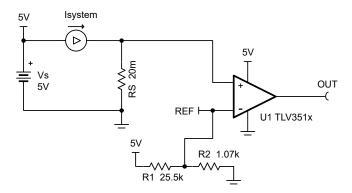


Figure 7-7. Current Sensing



7.2.1.1 Design Requirements

For this design, follow these design requirements:

- Alert (overcurrent) event occurs when system current (Isystem) reaches 10A
- Alert signal (OUT) is active high
- Operate from a 5V power supply

7.2.1.2 Detailed Design Procedure

To minimize power dissipation and voltage drop across the shunt resistor (RS), a value of $20m\Omega$ is selected. Since the overcurrent level of 10A creates a 200mV drop across RS, R1 and R2 are calculated to create the voltage divider value of 200mV from the regulated 5V supply voltage. If the system is expected to operate close to the 10A maximum, hysteresis can be added to the design as shown in Non-Inverting Comparator With Hysteresis.

7.2.1.3 Application Curve

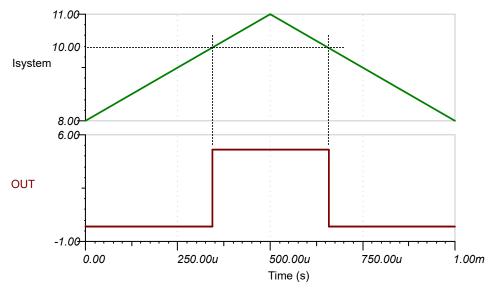


Figure 7-8. Current Sensing Results

7.3 Power Supply Recommendations

Due to the fast output edges, it is critical to have bypass capacitors on the supply pin to prevent supply ringing and false triggers and oscillations. Bypass the supply directly at *each* device with a low ESR 0.1μ F ceramic bypass capacitor directly between the (V+) pin and ground pins. Narrow peak currents will be drawn during the output transition time, particularly for the push-pull output device. These narrow pulses can cause un-bypassed supply lines and poor grounds to ring, possibly causing variation that can eat into the input voltage range and create an inaccurate comparison or even oscillations.

The device may be powered from both "split" supplies ((V+) &(V-)), or "single" supplies ((V+) and GND), with GND applied to the (V-) pin. Input signals must stay within the recommended input range for either type. Note that with a "split" supply the output will now swing "low" (V_{OL}) to (V-) potential and not GND.

7.4 Layout

7.4.1 Layout Guidelines

For accurate comparator applications it is important maintain a stable power supply with minimized noise and glitches. Output rise and fall times are in the tens of nanoseconds, and should be treated as high speed logic devices. The bypass capacitor should be as close to the supply pin as possible and connected to a solid ground plane, and preferably directly between the (V+) and GND pins.



Minimize coupling between outputs and inputs to prevent output oscillations. Do not run output and input traces in parallel unless there is a (V+) or GND trace between output to reduce coupling. When series resistance is added to inputs, place resistor close to the device. A low value (<100 ohms) resistor may also be added in series with the output to dampen any ringing or reflections on long, non-impedance controlled traces. For best edge shapes, controlled impedance traces with back-terminations should be used when routing long distances.

7.4.2 Layout Example

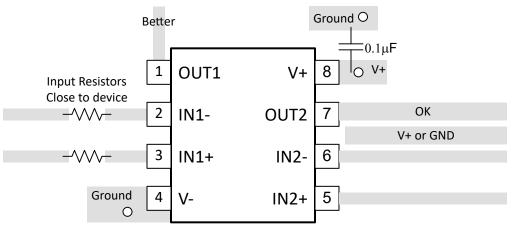


Figure 7-9. Dual Layout Example

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

Analog Engineers Circuit Cookbook: Amplifiers (See Comparators section) - SLYY137

Precision Design, Comparator with Hysteresis Reference Design— TIDU020

Window comparator circuit - SBOA221

Reference Design, Window Comparator Reference Design— TIPD178

Comparator with and without hysteresis circuit - SBOA219

Inverting comparator with hysteresis circuit - SNOA997

Non-Inverting Comparator With Hysteresis Circuit - SBOA313

A Quad of Independently Func Comparators - SNOA654

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments. All trademarks are the property of their respective owners.



8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
November 2024	*	Initial Release

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated